Photocouplers GaA{As Infrared LED & Photo IC

# TLP2710

#### 1. Applications

- Programmable Logic Controllers (PLCs)
- Battery Management System (BMS)
- Transistor Inverters

#### 2. General

The TLP2710 is a 5-Mbps low-power photocoupler in the small SO6L package. It is housed in a thin SO6L package of 2.3 mm (max). The TLP2710 has guaranteed the isolation voltage 5 kVrms and compliant with international safety standards for reinforced insulation. The TLP2710 consumes supply current ( $I_{DDL}/I_{DDH}$ ) of only 0.3 mA maximum over the entire operating temperature range of -40 to 125 °C and operates at a supply voltage as low as 2.7 V, contributing to a reduction in power consumption of various systems. The input forward current can be less than 1 mA maximum, allowing direct drive by a microcontroller. The detector has a totem-pole output stage with current sourcing and sinking capabilities. The TLP2710 has an internal Faraday shield that provides a guaranteed common-mode transient immunity of ±25 kV/µs.

#### 3. Features

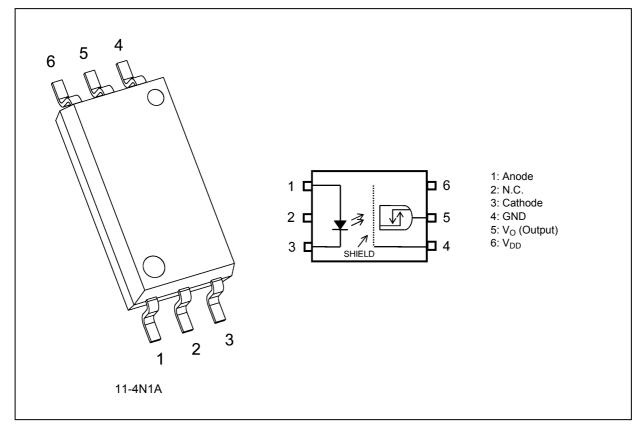
- (1) Package: SO6L
- (2) Data transfer rate: 5 MBd (typ.) (NRZ)
- (3) Supply current: 0.3 mA (max)
- (4) Threshold input current: 1.0 mA (max)
- (5) Supply voltage: 2.7 V to 5.5 V
- (6) Operating temperature: -40 to  $125 \ ^{\circ}\text{C}$
- (7) Propagation delay time: 250 ns (max)
- (8) Pulse width distortion: 30 ns (max)
- (9) Isolation voltage: 5000 Vrms (min)
- (10) Safety standards
  - UL-approved: UL1577, File No.E67349

cUL-approved: CSA Component Acceptance Service No.5A File No.E67349

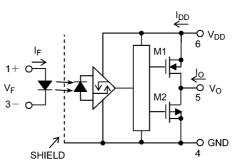
VDE-approved: EN60747-5-5, EN60065 or EN60950-1, EN62368-1 (Pending) (Note 1)

Note 1: When a VDE approved type is needed, please designate the Option (D4).

#### 4. Packaging and Pin Assignment



#### 5. Internal Circuit (Note)



Note: A  $0.1-\mu F$  bypass capacitor must be connected between pin 6 and pin 4.

#### 6. Principle of Operation

#### 6.1. Truth Table

| Input | LED | Output |
|-------|-----|--------|
| Н     | ON  | Н      |
| L     | OFF | L      |

#### 6.2. Mechanical Parameters

| Characteristics              | Dimension(Min) | Unit |
|------------------------------|----------------|------|
| Creepage distances           | 8.0            | mm   |
| Clearance distances          | 8.0            |      |
| Internal isolation thickness | 0.4            |      |

#### Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

|          | Characteristics                               |                               | Symbol                        | Note     | Rating     | Unit  |
|----------|---|-------------------------------|-------------------------------|----------|------------|-------|
| LED      | Input forward current                         |                               | I <sub>F</sub>                |          | 8          | mA    |
|          | Input forward current (pulsed)                |                               | I <sub>FP</sub>               |          | 40         |       |
|          | Input forward current derating (pulsed)       | $(T_a \ge 110 \text{ °C})$    | $\Delta I_{FP} / \Delta T_a$  |          | -1         | mA/°C |
|          | Peak transient input forward current          |                               | I <sub>FPT</sub>              | (Note 1) | 1          | A     |
|          | Peak transient input forward current derating | (T <sub>a</sub> ≥ 110 °C)     | $\Delta I_{FPT} / \Delta T_a$ |          | -25        | mA/°C |
|          | Input power dissipation                       |                               | PD                            |          | 20         | mW    |
|          | Input power dissipation derating              | $(T_a \ge 110 \ ^\circ C)$    | $\Delta P_D / \Delta T_a$     |          | -0.5       | mW/°C |
|          | Input reverse voltage                         |                               | V <sub>R</sub>                |          | 5          | V     |
| Detector | Output current                                |                               | I <sub>O</sub>                |          | 10         | mA    |
|          | Output voltage                                |                               | Vo                            |          | 6          | V     |
|          | Supply voltage                                |                               | V <sub>DD</sub>               |          | 6          |       |
|          | Output power dissipation                      |                               | Po                            |          | 20         | mW    |
|          | Output power dissipation derating             | $(T_a \ge 110 \ ^\circ C)$    | $\Delta P_0 / \Delta T_a$     |          | -0.5       | mW/°C |
| Common   | Operating temperature                         |                               | T <sub>opr</sub>              |          | -40 to 125 | °C    |
|          | Storage temperature                           |                               | T <sub>stg</sub>              |          | -55 to 125 |       |
|          | Lead soldering temperature                    | (10 s)                        | T <sub>sol</sub>              |          | 260        |       |
|          | Isolation voltage                             | (AC, 60 s, R.H. $\leq$ 60 % ) | BV <sub>S</sub>               | (Note 2) | 5000       | Vrms  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW)  $\leq$  1  $\mu$ s, 300 pps

#### 8. Recommended Operating Conditions (Note)

| Characteristics         | Symbol              | Note     | Min | Тур.    | Max | Unit |
|-------------------------|---------------------|----------|-----|---------|-----|------|
| Input on-state current  | I <sub>F(ON)</sub>  | (Note 1) | 2   | _       | 6   | mA   |
| Input off-state voltage | V <sub>F(OFF)</sub> | (Note 1) | 0   |         | 0.8 | V    |
| Supply voltage          | V <sub>DD</sub>     | (Note 2) | 2.7 | 3.3 / 5 | 5.5 | V    |
| Operating temperature   | T <sub>opr</sub>    | (Note 2) | -40 |         | 125 | °C   |

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this datasheet should also be considered.

Note: A ceramic capacitor (0.1 µF) should be connected between pin 6 and pin 4 to stabilize the operation of a highgain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

Note 1: The rise and fall times of the input on-current should be less than 0.5  $\mu s.$ 

Note 2: Denotes the operating range, not the recommended operating condition.

Note 2: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

#### 9. Electrical Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C, V<sub>DD</sub> = 2.7 to 5.5 V)

| Characteristics                               | Symbol                    | Test<br>Circuit | Test Condition  | Min                   | Тур.                   | Max | Unit  |
|---|---------------------------|-----------------|---|-----------------------|------------------------|-----|-------|
| Input forward voltage                         | V <sub>F</sub>            |                 | I <sub>F</sub> = 2 mA   | 1.2                   | —                      | 1.9 | V     |
|   |                           |                 | I <sub>F</sub> = 2 mA, T <sub>a</sub> = 25 °C                   | 1.4                   | 1.53                   | 1.7 |       |
| Input forward voltage temperature coefficient | $\Delta V_F / \Delta T_a$ |                 | I <sub>F</sub> = 2 mA   | _                     | -1.58                  | _   | mV/°C |
| Input reverse current                         | I <sub>R</sub>            |                 | V <sub>R</sub> = 5 V, T <sub>a</sub> = 25 °C                    |                       | _                      | 10  | μA    |
| Input capacitance                             | Ct                        |                 | V = 0 V, f = 1 MHz , T <sub>a</sub> = 25 °C                     | _                     | 20                     | _   | pF    |
| Low-level output voltage                      | V <sub>OL</sub>           | Fig.            | I <sub>O</sub> = 20 μA, V <sub>F</sub> = 0.8 V                  | _                     | —                      | 0.1 | V     |
|   |                           | 12.1.1          | I <sub>O</sub> = 3.2 mA, V <sub>F</sub> = 0.8 V                 | _                     | —                      | 0.4 |       |
| High-level output voltage                     | V <sub>OH</sub>           | Fig.            | I <sub>O</sub> = -20 μA, I <sub>F</sub> = 2 mA                  | V <sub>DD</sub> - 0.1 | V <sub>DD</sub> - 0.01 | _   |       |
|   |                           | 12.1.2          | I <sub>O</sub> = -3.2 mA, I <sub>F</sub> = 2 mA                 | V <sub>DD</sub> - 1.0 | V <sub>DD</sub> - 0.25 | _   |       |
| Low-level supply current                      | I <sub>DDL</sub>          | Fig.<br>12.1.3  | I <sub>F</sub> = 0 mA   | _                     | _                      | 0.3 | mA    |
| High-level supply current                     | I <sub>DDH</sub>          | Fig.<br>12.1.4  | I <sub>F</sub> = 2 mA   | —                     | —                      | 0.3 |       |
| Threshold input current (L/H)                 | I <sub>FLH</sub>          |                 | I <sub>O</sub> = -3.2 mA, V <sub>O</sub> > V <sub>DD</sub> - 1V |                       |                        | 1.0 |       |

Note: All typical values are at  $V_{DD}$  = 5 V,  $T_a$  = 25 °C, unless otherwise noted

#### 10. Isolation Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

| Characteristics                     | Symbol         | Note     | Test Condition                  | Min                | Тур.             | Max | Unit |
|-------------------------------------|----------------|----------|---------------------------------|--------------------|------------------|-----|------|
| Total capacitance (input to output) | CS             | (Note 1) | V <sub>S</sub> = 0 V, f = 1 MHz |                    | 0.8              |     | pF   |
| Isolation resistance                | R <sub>S</sub> | (Note 1) | $V_S$ = 500 V, R.H. $\leq$ 60 % | $1 \times 10^{12}$ | 10 <sup>14</sup> | _   | Ω    |
| Isolation voltage                   | BVS            | (Note 1) | AC, 60 s                        | 5000               | _                | _   | Vrms |
|                                     |                |          | AC, 1 s, in oil                 | _                  | 10000            |     |      |
|                                     |                |          | DC, 60 s, in oil                | _                  | 10000            | _   | Vdc  |

Note 1: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

## 11. Swithcing Characteristics (Note) (Unless otherwise specified, $T_a$ = -40 to 125 °C, $V_{DD}$ = 2.7 to 5.5 V)

| Characteristics                                  | Symbol                             | Note                  | Test<br>Circuit | Test Condition   | Min | Тур. | Max | Unit  |
|--|------------------------------------|-----------------------|-----------------|--|-----|------|-----|-------|
| Propagation delay time<br>(L/H)                  | t <sub>pLH</sub>                   | (Note 1)              | Fig.<br>12.1.5  | V <sub>IN</sub> = 3.3 V, R <sub>T</sub> = 820 Ω                  | 80  | —    | 250 | ns    |
| Propagation delay time<br>(H/L)                  | t <sub>pHL</sub>                   |                       |                 |  | 60  | —    | 250 |       |
| Pulse width distortion                           | t <sub>pHL</sub> -t <sub>pLH</sub> |                       |                 |  | —   | —    | 50  |       |
| Propagation delay skew (device to device)        | t <sub>psk</sub>                   | (Note 1),<br>(Note 2) |                 |  | -65 | -    | 65  |       |
| Propagation delay time<br>(L/H)                  | t <sub>pLH</sub>                   | (Note 1)              |                 | V <sub>IN</sub> = 5 V, R <sub>T</sub> = 1.6 kΩ                   | 80  | —    | 250 |       |
| Propagation delay time<br>(H/L)                  | t <sub>pHL</sub>                   |                       |                 |  | 60  | —    | 250 |       |
| Pulse width distortion                           | t <sub>pHL</sub> -t <sub>pLH</sub> |                       |                 |  | —   | —    | 50  |       |
| Propagation delay skew (device to device)        | t <sub>psk</sub>                   | (Note 1),<br>(Note 2) |                 |  | -65 | -    | 65  |       |
| Propagation delay time<br>(L/H)                  | t <sub>pLH</sub>                   | (Note 1)              | Fig.<br>12.1.6  | I <sub>F</sub> = 2 mA, R = 100 Ω                                 | 80  | —    | 250 |       |
| Propagation delay time<br>(H/L)                  | t <sub>pHL</sub>                   |                       |                 |  | 60  | —    | 250 |       |
| Pulse width distortion                           | t <sub>pHL</sub> -t <sub>pLH</sub> |                       |                 |  | _   | _    | 30  | 1     |
| Propagation delay skew (device to device)        | t <sub>psk</sub>                   | (Note 1),<br>(Note 2) |                 |  | -65 | —    | 65  |       |
| Rise time  | t <sub>r</sub>                     | (Note 1)              | Fig.<br>12.1.5  |  | —   | 11   | —   |       |
| Fall time  | t <sub>f</sub>                     |                       |                 |  | —   | 13   | _   |       |
| Common-mode transient<br>immunity at output high | CM <sub>H</sub>                    |                       | Fig.<br>12.1.7  | V <sub>IN</sub> = 3.3 V / 5 V,<br>V <sub>DD</sub> = 3.3 V / 5 V, | ±25 | ±40  | —   | kV/μs |
| Common-mode transient<br>immunity at output low  | CML                                |                       |                 | V <sub>CM</sub> = 1000 V <sub>p-p</sub> , T <sub>a</sub> = 25 °C |     |      |     |       |

Note: All typical values are at  $V_{DD}$  = 5 V,  $T_a$  = 25 °C, unless otherwise noted.

Note: Recommendation input resistance conditions

 $\cdot V_{IN} = 3.3 \text{ V}$  :  $R_1 = R_2 = 430 \Omega$ 

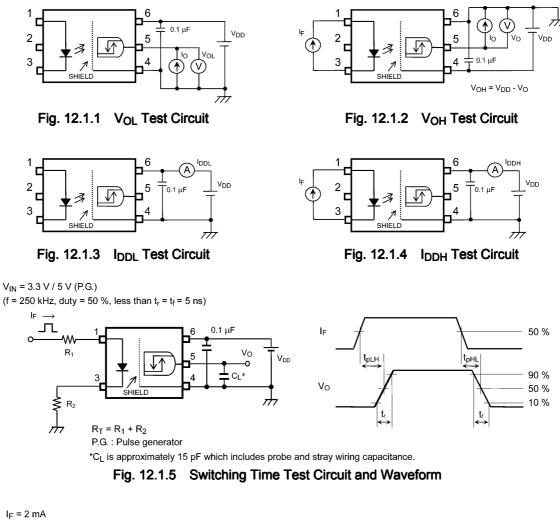
 $\cdot$  V<sub>IN</sub> = 5 V : R<sub>1</sub> = R<sub>2</sub> = 820  $\Omega$ 

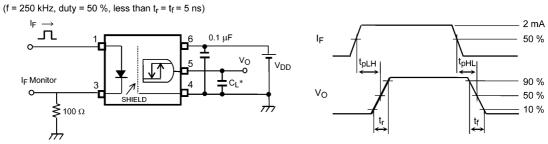
Note 1: f = 250 kHz, duty = 50 %, input current  $t_r = t_f = 5$  ns,  $C_L$  is approximately 15 pF which includes probe and stray wiring capacitance.

Note 2: The propagation delay skew, t<sub>psk</sub>, is equal to the magnitude of the worst-case difference in t<sub>pHL</sub> and/or t<sub>pLH</sub> that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc).

#### 12. Test Circuits and Characteristics Curves

#### 12.1. Test Circuits





 $^{*}C_{L}$  is approximately 15 pF which includes probe and stray wiring capacitance.

Fig. 12.1.6 Switching Time Test Circuit and Waveform

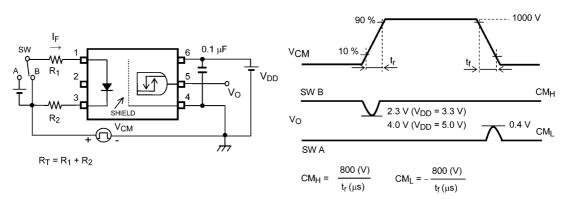


Fig. 12.1.7 Common-Mode Transient Immunity and Waveform

#### 13. Soldering and Storage

#### 13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

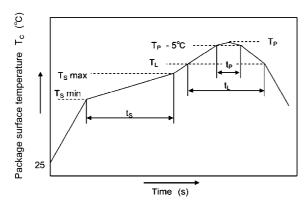
• When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



|  | Symbol         | Min | Max | Unit |
|--|----------------|-----|-----|------|
| Preheat temperature  | Τs             | 150 | 200 | °C   |
| Preheat time   | ts             | 60  | 120 | s    |
| Ramp-up rate $(T_L \text{ to } T_P)$                       |                |     | 3   | °C/s |
| Liquidus temperature                                       | TL             | 2   | 17  | °C   |
| Time above T <sub>L</sub>                                  | tL             | 60  | 150 | s    |
| Peak temperature   | Τ <sub>Ρ</sub> |     | 260 | °C   |
| Time during which $T_c$ is between ( $T_P - 5$ ) and $T_P$ | t <sub>P</sub> |     | 30  | s    |
| Ramp-down rate $(T_P \text{ to } T_L)$                     |                |     | 6   | °C/s |

Fig. 13.1.1 An Example of a Temperature Profile When Lead(Pb)-free Solder Is Used

• When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

• When using soldering Iron

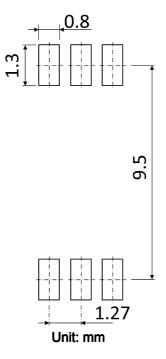
Complete soldering within 10 seconds for lead temperature not exceeding 260  $^\circ \! C$  or within 3 seconds not exceeding 350  $^\circ \! C$ 

Heating by soldering iron must be done only once per lead.

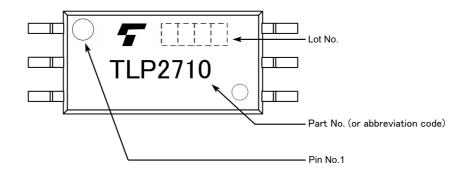
#### 13.2. Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5  $^\circ C$  to 35  $^\circ C$  and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- $\bullet$   $\;$  When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

#### 14. Land Pattern Dimensions (for reference only)



#### 15. Marking



#### 16. EN60747-5-5 Option (D4) Specification

- Part number: TLP2710 (Note 1)
  - The following part naming conventions are used for the devices that have been qualified according to option (D4) of EN60747.

Example: TLP2710(D4-TP,E(T

D4: EN60747 option

TP: Tape type

E: [[G]]/RoHS COMPATIBLE (Note 2)

T: Domestic ID (Country / Region of origin: Thailand)

Note 1: Use TOSHIBA standard type number for safety standard application.

e.g., TLP2710(D4-TP,E(T  $\rightarrow$  TLP2710

Note 2: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

| Description   | Symbol   | Rating  | Unit           |
|---|--|---|----------------|
| Application classification  |  |   |                |
| for rated mains voltage $\leq$ 600 Vrms for rated mains voltage $\leq$ 1000 Vrms  |  | I-IV<br>I-III   | _              |
| Climatic classification   |  | 55 / 125 / 21   | _              |
| Pollution degree  |  | 2   | _              |
| Maximum operating insulation voltage  | VIORM  | 1230  | Vpeak          |
| Input to output test voltage, Method A $V_{pr}$ = 1.6 × $V_{IORM}$ , type and sample test $t_p$ = 10 s, partial discharge < 5 pC  | Vpr  | 1970  | Vpeak          |
| Input to output test voltage, Method B<br>$V_{pr}$ =1.875 × V <sub>IORM</sub> , 100 % production test<br>$t_p$ = 1 s, partial discharge < 5 pC  | V <sub>pr</sub>                                      | 2310  | Vpeak          |
| Highest permissible overvoltage<br>(transient overvoltage, t <sub>pr</sub> = 60 s)  | VTR  | 8000  | Vpeak          |
| Safety limiting values (max. permissible ratings in case of fault,<br>also refer to thermal derating curve)<br>current (input current I <sub>F</sub> , P <sub>so</sub> = 0)<br>power (output or total power dissipation)<br>temperature | I <sub>si</sub><br>P <sub>so</sub><br>T <sub>s</sub> | 250<br>400<br>150   | mA<br>mW<br>°C |
| Insulation resistance $V_{IO} = 500 \text{ V}, \text{ T}_a = 25 \text{ °C}$<br>$V_{IO} = 500 \text{ V}, \text{ T}_a = 100 \text{ °C}$<br>$V_{IO} = 500 \text{ V}, \text{ T}_a = \text{T}_s$   | R <sub>si</sub>                                      | ≥ 10 <sup>12</sup><br>≥ 10 <sup>11</sup><br>≥ 10 <sup>9</sup> | Ω              |

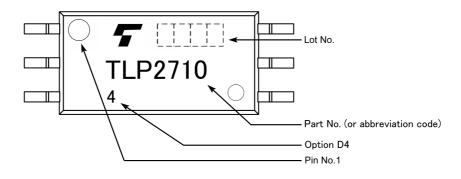
Fig. 16.1 EN60747 Isolation Characteristics

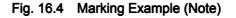
| Minimum creepage distance    | Cr  | 8.0 mm |
|------------------------------|-----|--------|
| Minimum clearance            | CI  | 8.0 mm |
| Minimum insulation thickness | ti  | 0.4 mm |
| Comparative tracking index   | CTI | 175    |

- Note: If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e.g., at a standard distance between soldering eye centers of 9.5 mm). If this is not permissible, the user shall take suitable measures.
- Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.



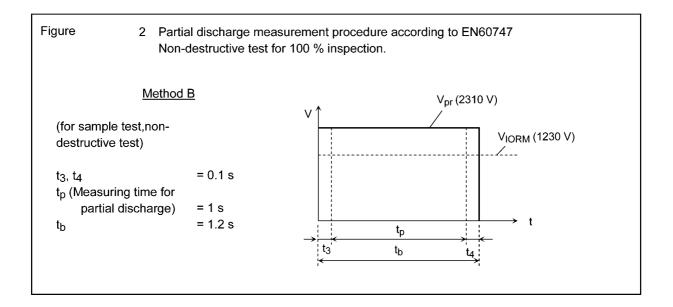
Fig. 16.3 Marking on Packing

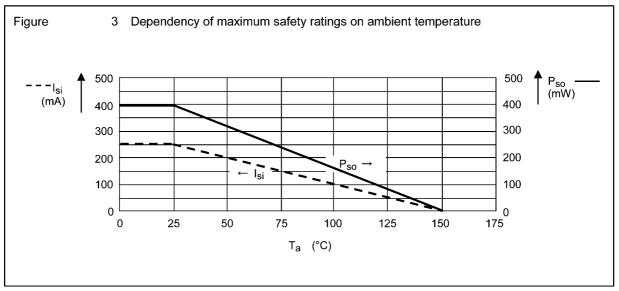




Note: The above marking is applied to the photocouplers that have been qualified according to option (D4) of EN60747.

| 5   | -           | surement procedure according to EN60747<br>alification and sampling tests. |
|---|-------------|--|
| Metho                                     | <u>d A</u>  | VINITIAL(8 KV)   |
| (for type and sampling destructive tests) | tests,      | V V V <sub>pr</sub> (1970 V)   |
| t <sub>1</sub> , t <sub>2</sub>           | = 1 to 10 s | V <sub>IORM</sub> (1230 V)   |
| t3, t4                                    | = 1 s       |  |
| t <sub>p</sub> (Measuring time for        |             |  |
| partial discharge)                        | = 10 s      | $0 \xrightarrow{\mu} t \xrightarrow{\mu} t$                                |
| t <sub>b</sub>                            | = 12 s      | $t_3$ $t_p$ $t_4$  |
| t <sub>ini</sub>                          | = 60 s      | $t_1$ $t_{ini}$ $t_2$ $t_b$  |
|   |             |  |







#### 17. Specifications for Embossed-Tape Packing (TP)

#### 17.1. Applicable Package

| Package Name | Product Type                       |
|--------------|------------------------------------|
| SO6L         | Long creepage mini flat<br>coupler |

#### 17.2. Product Naming Conventions

Type of package used for shipment is denoted by a symbol suffix after a part number. The method of classification is as below.

Example) TLP2710(TP,E(T

Part number: TLP2710 Tape type: TP [[G]]/RoHS COMPATIBLE: E **(Note 1)** T: Domestic ID (Country / Region of origin: Thailand)

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

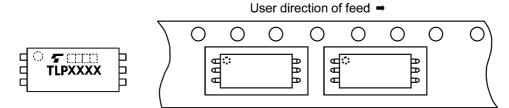
RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

#### 17.3. Tape Dimensions Specification

| Specification | Division | Packing Amount<br>(A unit per reel) |
|---------------|----------|-------------------------------------|
| TP            | _        | 1500                                |

#### 17.3.1. Orientation of Device in Relation to Direction of Feed

Device orientation in the carrier cavities as shown in the following figure.





per reel: 1500 pcs

#### 17.3.2. Empty Device Recesses

| Characteristics                                    | Standard                 | Remarks  |
|--|--------------------------|--|
| occurrences of 2 more<br>successive empty cavities |                          | Within any given 40-mm section of tape, not including leader and trailer |
| Single empty cavity                                | 6 devices (max) per reel | Not including leader and trailer   |

#### 17.3.3. Tape Leader and Trailer

The start of the tape has 14 or more empty holes. The end of the tape has 34 or more empty holes and more than 30 mm only for a cover tape.

#### 17.3.4. Tape Dimensions

Tape material: Plastic (for protection against static electricity)

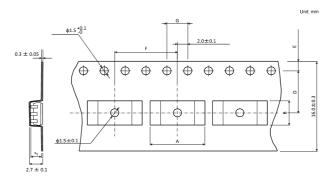
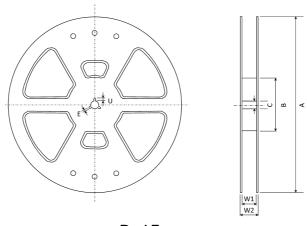


 Table
 Tape Dimensions (unit: mm, tolerance: ±0.1)

| Symbol         | Dimension | Remark   |
|----------------|-----------|--|
| А              | 10.4      | _  |
| В              | 4.24      | —  |
| D              | 7.5       | Center line of embossed cavity and sprocket hole             |
| E              | 1.75      | Distance between tape edge and sprocket hole center          |
| F              | 12.0      | Cumulative error +0.1/-0.3 (max) per 10 empty cavities holes |
| G              | 4.0       | Cumulative error +0.1/-0.3 (max) per 10 sprocket holes       |
| K <sub>0</sub> | 2.4       | Internal space   |

#### 17.3.5. Reel Specification

Material: Plastic (for protection against static electricity)



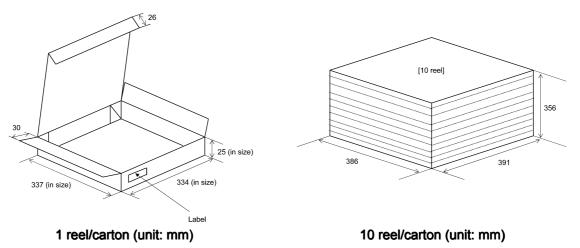
**Reel Forms** 

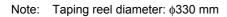
| Symbol | Dimension             |
|--------|-----------------------|
| А      | $\varphi 330\pm2.0$   |
| В      | $\varphi 100 \pm 1.0$ |
| С      | $\varphi 13 \pm 0.5$  |
| E      | $2.0\pm0.5$           |
| U      | $4.0\pm0.5$           |
| W1     | 17.4 ± 1.0            |
| W2     | $21.4\pm1.0$          |

#### Table Reel Dimensions (unit: mm)

#### 17.4. Packing (Note)

Either one reel or ten reels of photocouplers are packed in a shipping carton.





#### 17.5. Label Format

(1) Carton: The label provides the part number, quantity, lot number, the Toshiba logo, etc.(2) Reel: The label provides the part number, the taping name, quantity, lot number, etc.

#### 17.6. Ordering Information

When placing an order, please specify the part number, tape type and quantity as shown in the following example.

Example) TLP2710(TP,E 1500 pcs

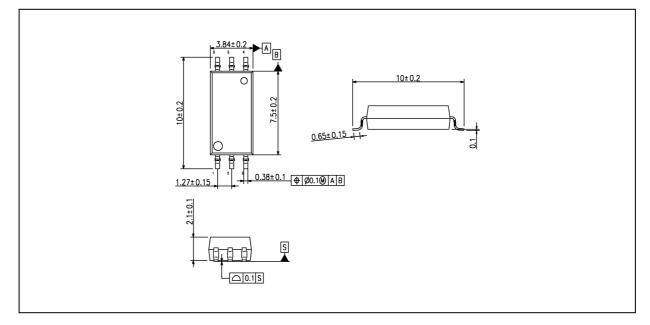
Part number: TLP2710 Tape type: TP (12-mm pitch) [[G]]/RoHS COMPATIBLE: E **(Note 1)** Quantity (must be a multiple of 1500): 1500 pcs

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

#### Package Dimensions

Unit: mm



Weight: 0.126 g (typ.)

Package Name(s)

TOSHIBA: 11-4N1A

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